WHAT IS CLAIMED IS:

1. A method of producing a photovoltaic element comprising the steps of:

immersing in an electrolytic solution a

5 photovoltaic element comprising a back surface reflecting layer, a semiconductor layer and a transparent electrode layer successively stacked on a substrate;

applying a forward voltage to the photovoltaic

element to effect an electrolytic treatment to reduce
the transparent electrode layer in a short-circuit
portion of the photovoltaic element, thereby
selectively removing a short-circuit current path in
the photovoltaic element due to a defect,

wherein a voltage gradient when the forward voltage applied to the photovoltaic element is caused to drop to 0 V or a such forward voltage as to effect no reduction reaction of the transparent electrode layer is -15 V/s to -0.1 V/s.

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2. The method of producing a photovoltaic element according to claim 1, wherein the time period during which the forward voltage is caused to drop is 0.3 second or more.

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3. The method of producing a photovoltaic element according to claim 1, wherein the forward

voltage is not less than the open circuit voltage of the photovoltaic element.

- 4. The method of producing a photovoltaic

 5 element according to claim 1, wherein the applied voltage is in a form of a trapezoidal wave that alternates between the forward voltage not less than the open circuit voltage of the photovoltaic element and 0 V or such a forward voltage as to effect no

 10 reduction reaction of the transparent electrode layer.
- 5. The method of producing a photovoltaic element according to claim 1, wherein the applied voltage is in a form of a sawtooth wave that

 15 alternates between the forward voltage not less than the open circuit voltage of the photovoltaic element and 0 V or such a forward voltage as to effect no reduction reaction of the transparent electrode layer does not occur.

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- 6. The method of producing a photovoltaic element according to claim 1, wherein the applied voltage is applied a plural number of times.
- 7. The method of producing a photovoltaic element according to claim 1, wherein the photovoltaic element is cleaned with water and dried

after the electrolytic treatment.

- 8. The method of producing a photovoltaic element according to claim 1, wherein the electrical conductivity of the electrolytic solution is 20 to 100 mS/cm.
- 9. The method of producing a photovoltaic element according to claim 1, wherein the temperature of the electrolytic solution is within the temperature range of 20°C to 80°C.
- 10. The method of producing a photovoltaic element according to claim 1, wherein the

 15 photovoltaic element is a thin-film solar cell.